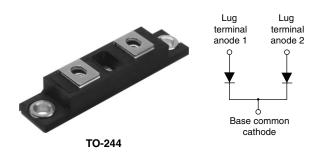
Vishay High Power Products

HEXFRED[®] Ultrafast Soft Recovery Diode, 320 A



SHA

PRODUCT SUMMARY				
I _{F(AV)}	320 A			
V _R	400 V			
I _{F(DC)} at T _C	255 A at 85 °C			

FEATURES

- Very low Q_{rr} and t_{rr}
- Lead (Pb)-free
- Designed and qualified for industrial level

BENEFITS

- Reduced RFI and EMI
- · Reduced snubbing

DESCRIPTION

HEXFRED[®] diodes are optimized to reduce losses and EMI/RFI in high frequency power conditioning systems. An extensive characterization of the recovery behavior for different values of current, temperature and dl/dt simplifies the calculations of losses in the operating conditions. The softness of the recovery eliminates the need for a snubber in most applications. These devices are ideally suited for power converters, motors drives and other applications where switching losses are significant portion of the total losses.

ABSOLUTE MAXIMUM RATINGS					
PARAMETER	SYMBOL	TEST CONDITIONS	MAX.	UNITS	
Cathode to anode voltage	V _R		400	V	
		T _C = 25 °C	420		
Continuous forward current	I current I_F $T_C = 85 ^{\circ}C$		255	•	
		T _C = 115 °C	160	A	
Single pulse forward current	I _{FSM}	Limited by junction temperature	1200		
Non-repetitive avalanche energy	E _{AS}	L = 100 μ H, duty cycle limited by maximum T _J	1.4	mJ	
Maximum power dissipation P _D		T _C = 25 °C	625	W	
		T _C = 100 °C	250	vv	
Operating junction and storage temperature range	T _J , T _{Stg}		- 55 to 150	°C	

ELECTRICAL SPECIFICATIONS (T _J = 25 °C unless otherwise specified)							
PARAMETER	SYMBOL	TEST CONDITIONS		MIN.	TYP.	MAX.	UNITS
Cathode to anode breakdown voltage	V _{BR}	I _R = 100 μA		400	-	-	
		I _F = 160 A		-	1.10	1.35	v
Maximum forward voltage	V_{FM}	I _F = 320 A	See fig. 1	-	1.30	1.54	
		I _F = 160 A, T _J = 125 °C		-	1.00	1.20	
Maximum reverse leakage current	I _{RM}	$T_{J} = 125 \text{ °C}, V_{R} = 400 \text{ V}$ See fig. 2		-	0.9	3	mA
Junction capacitance	CT	V _R = 200 V See fig. 3		-	370	500	pF
Series inductance	L _S	From top of terminal hole to mounting plane - 5.0 -		nH			

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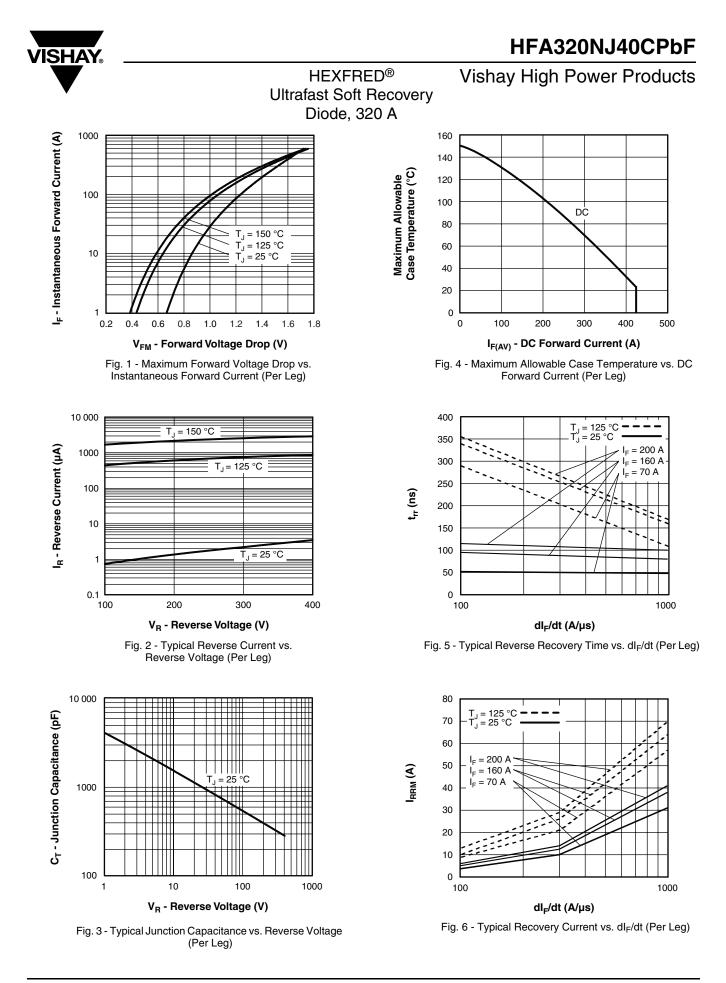
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DYNAMIC RECOVERY CHARACTERISTICS (T _J = 25 °C unless otherwise specified)								
PARAMETER	SYMBOL	TEST CO	MIN.	TYP.	MAX.	UNITS		
		$I_F = 1.0 \text{ A}, \text{ d}I_F/\text{d}t = 2$	200 A/µs, V _R = 30 V	-	45	-		
Reverse recovery time See fig. 5	t _{rr}	T _J = 25 °C		-	90	140	ns	
		T _J = 125 °C		-	290	440		
Peak recovery current	I _{RRM}	T _J = 25 °C		-	8.7	20	^	
See fig. 6		IRRM	T _J = 125 °C	$I_{\rm F} = 160 {\rm A}$	-	18	30	A
Reverse recovery charge	0	T _J = 25 °C	dI _F /dt = 200 A/μs V _B = 200 V	-	420	1100	nC	
See fig. 7	Q_{rr} $T_J = 1$	Qrr	T _J = 125 °C		-	2600	7000	nc
Peak rate of recovery current	dl(rec)M/dt	T _J = 25 °C		-	300	-	A./a	
See fig. 8		T _J = 125 °C		-	280	-	A/μs	

THERMAL - MECHANICAL SPECIFICATIONS						
PARAMETER		SYMBOL	MIN.	TYP.	MAX.	UNITS
Maximum junction and storage temperature r	ange	T _J , T _{Stg}	- 55	-	150	°C
Thermal resistance, junction to case	per leg	D	-	-	0.19	
mermai resistance, junction to case	per module	R _{thJC}	-	-	0.095	°C/W K/W
Typical thermal resistance, case to heatsink		R _{thCS}	-	0.10	-	
Weight			-	68	-	g
Weight			-	2.4	-	oz.
Mounting torque	(1)		30 (3.4)	-	40 (4.6)	NL
Mounting torque	center hole		12 (1.4)	-	18 (2.1)	N ⋅ m (lbf ⋅ in)
Terminal torque			30 (3.4)	-	40 (4.6)	
Vertical pull			-	-	80	lla fa la
2" lever pull			-	-	35	lbf ∙ in

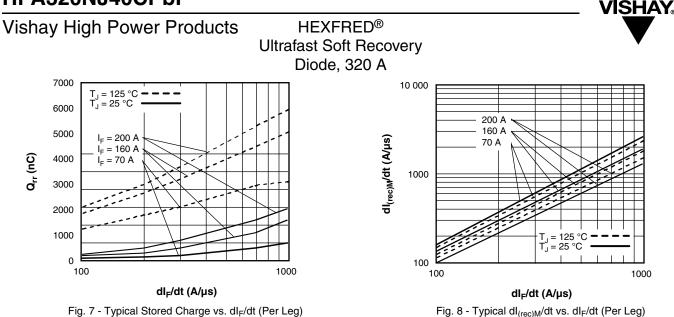
Note

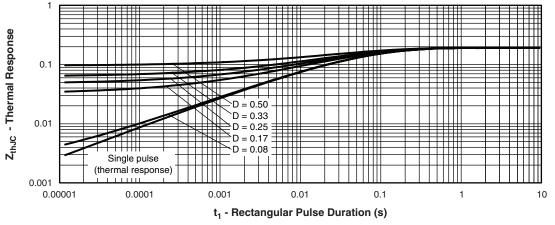
(1) Mounting surface must be smooth, flat, free of burrs or other protrusions. Apply a thin even film or thermal grease to mounting surface. Gradually tighten each mounting bolt in 5 to 10 lbf · in steps until desired or maximum torque limits are reached.



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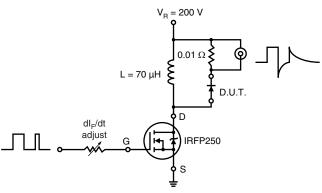
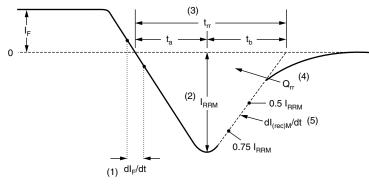


Fig. 10 - Reverse Recovery Parameter Test Circuit



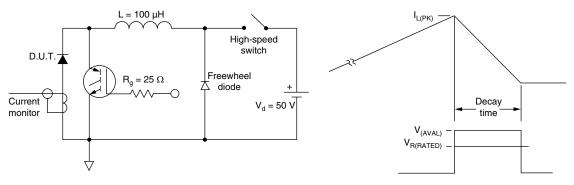
 dl_F/dt - rate of change of current through zero crossing (4) ${\rm Q}_{\rm rr}$ - area under curve defined by ${\rm t}_{\rm rr}$ and ${\rm I}_{\rm RRM}$

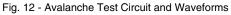
(2) I_{RRM} - peak reverse recovery current

(3) $t_{\rm rr}$ - reverse recovery time measured from zero crossing point of negative going ${\rm I_F}$ to point where a line passing through 0.75 ${\rm I_{RRM}}$ and 0.50 ${\rm I_{RRM}}$ extrapolated to zero current.

 $Q_{rr} = \frac{t_{rr} \times I_{RRM}}{2}$

- (5) dI $_{\rm (rec)M}/\rm dt$ peak rate of change of current during t_b portion of $t_{\rm rr}$
- Fig. 11 Reverse Recovery Waveform and Definitions





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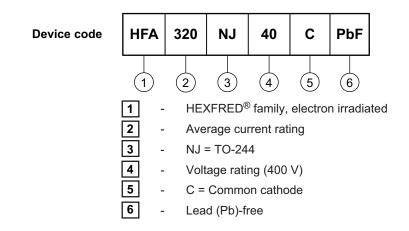
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ORDERING INFORMATION TABLE

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LINKS TO RELATED DOCUMENTS				
Dimensions	http://www.vishay.com/doc?95021			



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